



IFW

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application of: Jyunichi NAKAMURA et al. Confirmation No.: 5720  
Serial No.: 10/649,745 Art Unit: 2826  
Filed: August 28, 2003 Examiner: A. WILLIAMS  
For: **MULTILAYERED SUBSTRATE  
FOR SEMICONDUCTOR  
DEVICE** Atty Docket No: 060914-117-US

**AMENDMENT**

U.S. Patent and Trademark Office  
Randolph Building  
104 Dulany Street  
Alexandria, Virginia 22314

Sir:

In response to the outstanding Office Action dated December 9, 2004, please amend the above-referenced patent application in light of the following amendments and remarks.

**Amendments to the specification** begin on page 2 of this amendment;

**Amendment to the claims** begin at page 3; and

**Remarks** begin at page 5 of this amendment.